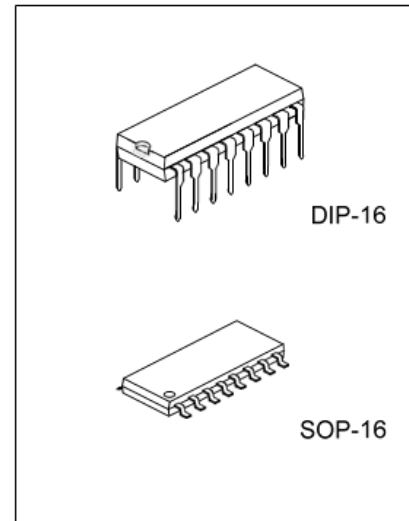


AUTOMOTIVE HALL EFFECT IGNITION CONTROLLER

Features

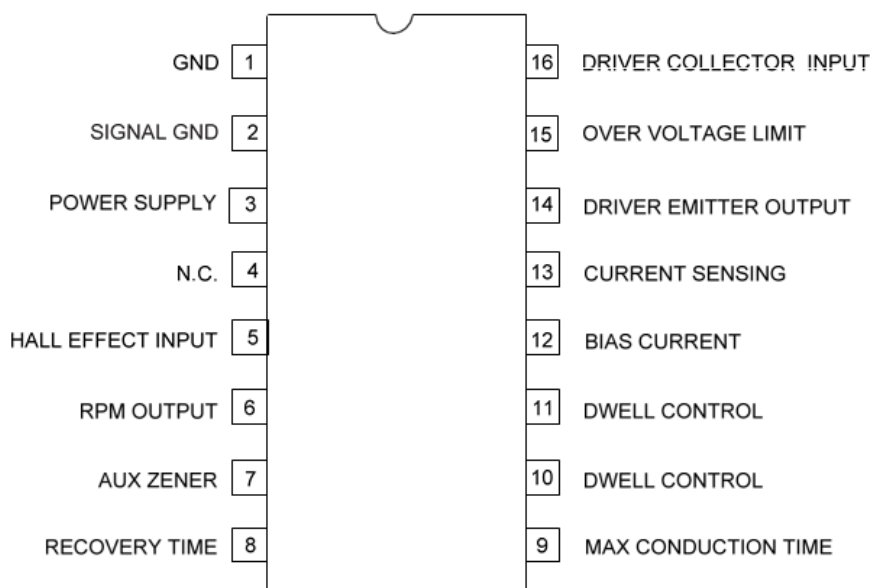
- Direct driving of the external power Darlington
- Coil current charging angle control
- Programmed coil current peak limitation
- When 94% nominal current not reached programmable dwell recovery time
- RPM output
- Has permanent conduction protection
- Overvoltage protection
- Internal supply Zener
- Reverse battery protection



Description

As an integrated electronic ignition controller for breakerless ignition systems which uses Hall effect sensors, the L497 drives an NPN external Darlington to control the coil current providing the required stored energy with low dissipation.

Pin Configuration



Absolute Maximum Rating

PARAMETER		SYMBOL	RATINGS	UNIT
D.C. Supply Current		I ₃	200	mA
Transient Supply Current	t _f fall time constant=100ms		800	mA
Supply Voltage		V ₃	Internal Limited to V _{Z3}	
RPM Voltage		V ₆	28	V
D.C. Driver Collector Current		I ₁₆	300	mA
Driver Collector Voltage		V ₁₆	28	V
Auxiliary Zener Current		I ₇	40	mA
D.C. Overvoltage Zener Current	Pulse t _{fall} =300μs	I ₁₅	15	mA
	t _{rep} Repetition Time≥3ms		35	mA
Reverse Battery Voltage if Application Circuit		V _R	-16	V
Junction Temperature		T _J	-55~ +150	°C
Storage Temperature		T _{STG}	-55~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Electrical Characteristics

(V_S=14.4V, -40 °C<T_J<125°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Min Operating Voltage	V ₃		3.5			V
Supply Current	I ₃	V ₃ =6V	5	18	25	mA
		V ₃ =4V	5		13	mA
Voltage Supply	V _S				28	V
Supply Clamping Zener Voltage	V _{Z3}	I _{Z3} =70mA	6.8	7.5	8.2	V
Input Voltage	V ₅	Low Status			0.6	V
		High Status	2.5			V
Input Current	I ₅	V ₅ =LOW	-400		-50	μA
Darlington Driver Saturation Current	V ₁₆₋₁₄	I ₁₄ =50mA			0.5	V
		I ₁₄ =180mA			0.9	V
Current Limit Sensing Voltage	V _{SENSE}	V _S =6~16V	260	330	400	mV
C _w Charge Current	I _{11C}	V _S =5.3~16V, V ₁₁ =0.5V, T=10~33ms	-11.0	-9.3	-7.8	μA
C _w Charge Current	I _{11D}	V _S =5.3~16V, V ₁₁ =0.5V, T=10~33ms	0.5	0.7	1.0	μA
C _w Charge Discharge ratio	I _{11C} /I _{11D}	V _S = 5.3~16V, V ₁₁ =0.5V, T=10~33ms (Note 1)	7.8		22.0	
Percentage of Output Current Determining the Slow Recovery Control Start (Note 2)	I _{SRC} /I _{SENSE}		90	94	98.5	%
Duration of Altered Small Control Ratio after SRC Function Start	T _{SRC}	C _{SRC} =1μF, R ₇ =62KΩ		0.8		s
External Darlington over V Prot Zener Voltage	V _{Z15}	I ₁₅ =5mA	20	25	30	V
		I ₁₅ =2mA	18	23	28	
Permanent Conduction Time	T _P	V ₅ =High, C _P =1μF, R ₇ =62KΩ		1.0		s
RPM Output Saturation Voltage	V _{6SAT}	I ₆ =18.5mA			0.5	V
		I ₆ =25mA			0.8	V
RPM Output Leakage Current	I _{6LEAK}	V _S =20V			50	μA
Auxiliary Zener Voltage	V _{Z7}	I ₇ =20mA	19		27	V
Reference Voltage	V ₁₂		1.0	1.2	1.3	V

Notes: 1. td/t desaturation ratio is given by: td/T=1/[1+I_{11C}/I_{11D}].

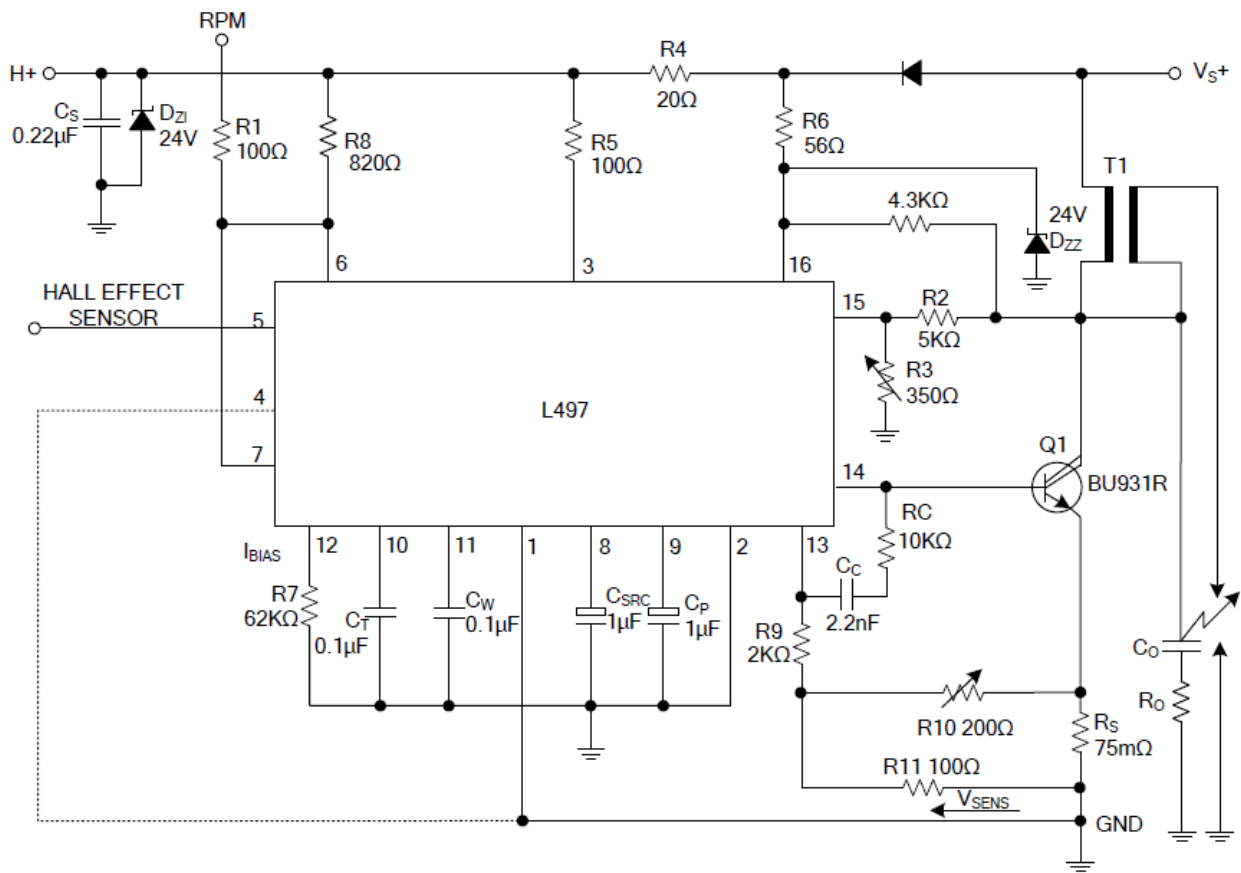
2. I_{SENSE}=I_{coil} when the external Darlington is in the active region.

Thermal Data

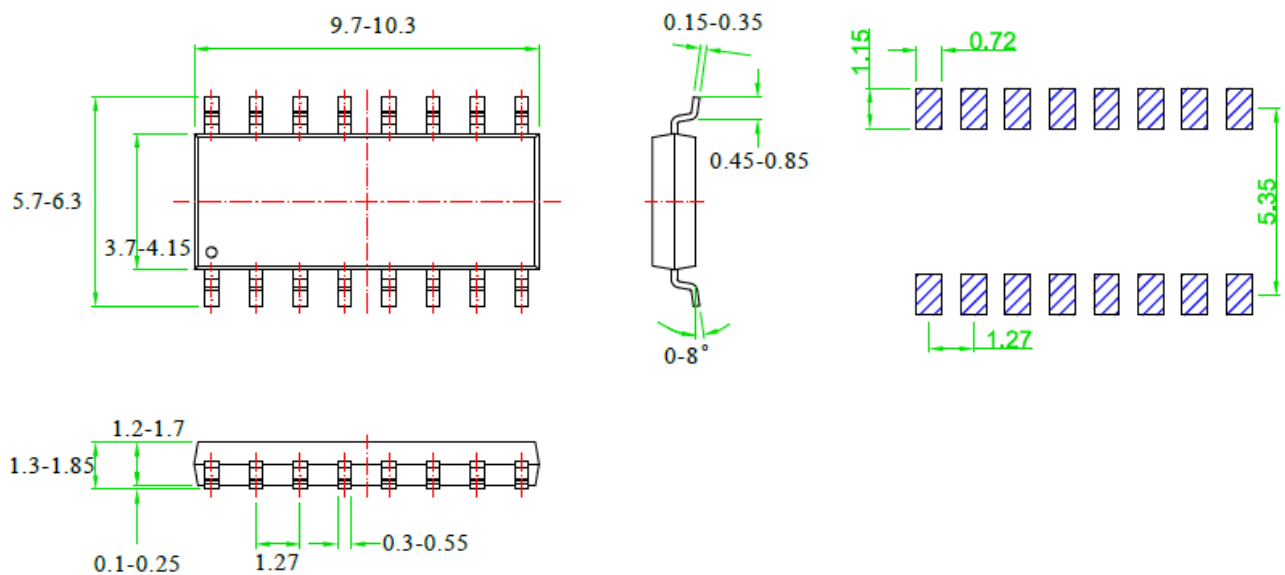
PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	DIP-16	θ_{JA}	90	$^{\circ}\text{C}/\text{W}$
	SOP-16		55 (Note)	$^{\circ}\text{C}/\text{W}$

Note: Thermal resistance junction Ambient with the device soldered on the middle of an Ambient supporting substrate measuring 15x20; 0.65mm thickness.

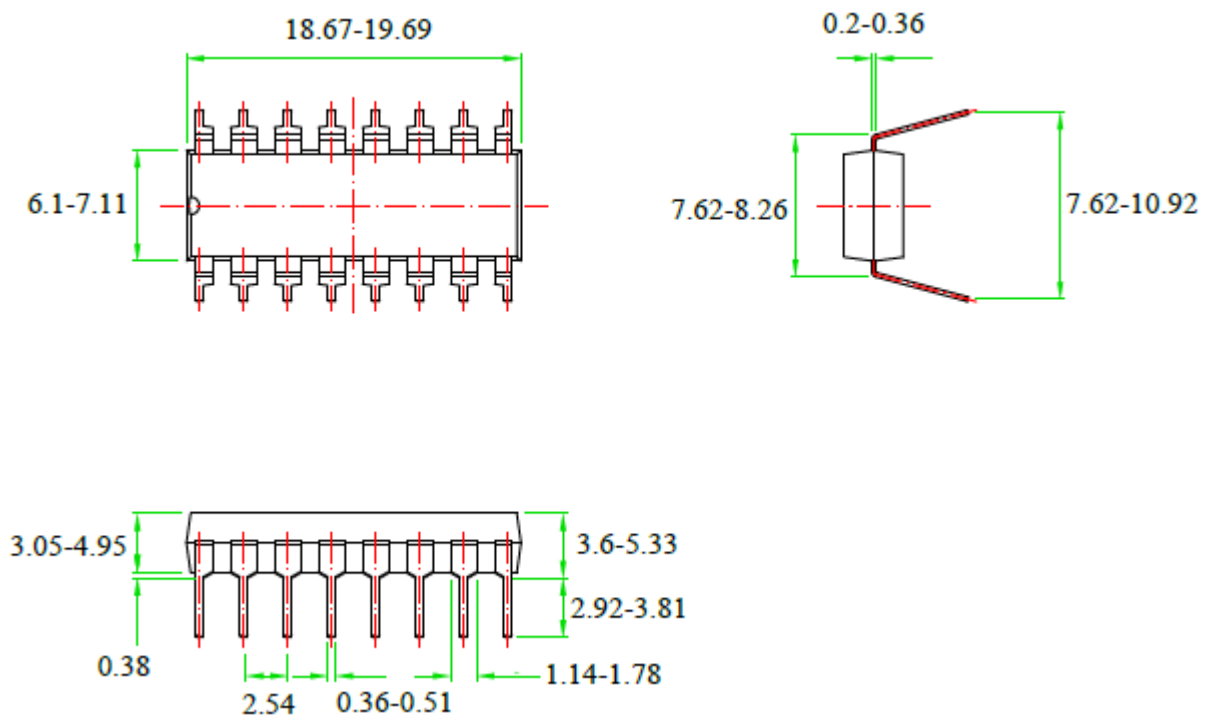
Typical Application Circuit



SOP-16 Package Dimensions



DIP-16 Package Dimensions



*All dimensions are in millimeters

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